

**Features:**

- Isolated mounting base 3000V~
- Pressure contact technology with increased power cycling capability
- Space and weight saving

Typical Applications

- Various rectifiers
- DC supply for PWM inverter

V_{RSM}	V_{RRM}	Type & Outline
2100V	2000V	MDx110-20-223F3
2300V	2200V	MDx110-22-223F3
2600V	2500V	MDx110-25-223F3

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled, $T_c=100^{\circ}C$	150			110	A
$I_{F(RMS)}$	RMS forward current		150			173	A
I_{RRM}	Repetitive peak current	at V_{RRM}	150			8	mA
I_{FSM}	Surge forward current	10ms half sine wave $V_R=0.6V_{RRM}$	150			2.6	kA
I^2t	I^2t for fusing coordination					33	$A^2s \cdot 10^3$
V_{FO}	Threshold voltage		150			0.85	V
r_F	Forward slope resistance					1.88	m Ω
V_{FM}	Peak forward voltage	$I_{FM}=330A$	25			1.55	V
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180° sine: Single side cooled per chip				0.33	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance case to heatsink	At 180° sine: Single side cooled per chip				0.20	$^{\circ}C/W$
V_{iso}	Isolation voltage	50Hz, R.M.S, t=1min, $I_{iso}:1mA(max)$		3000			V
F_m	Terminal connection torque(M5)				4		N·m
	Mounting torque(M6)				6		N·m
T_{stg}	Stored temperature			-40		125	$^{\circ}C$
W_t	Weight				170		g
Outline	223F3						

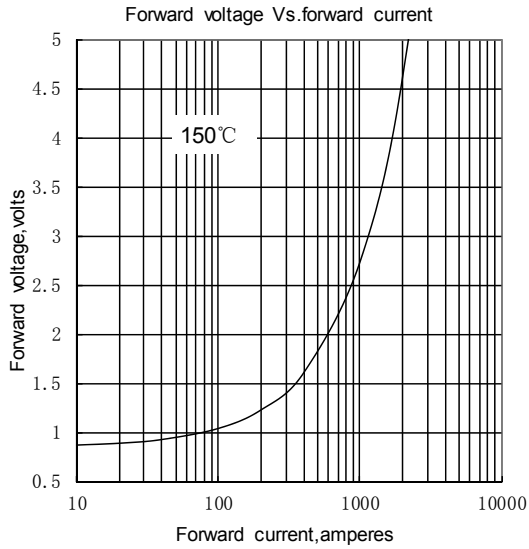


Fig.1

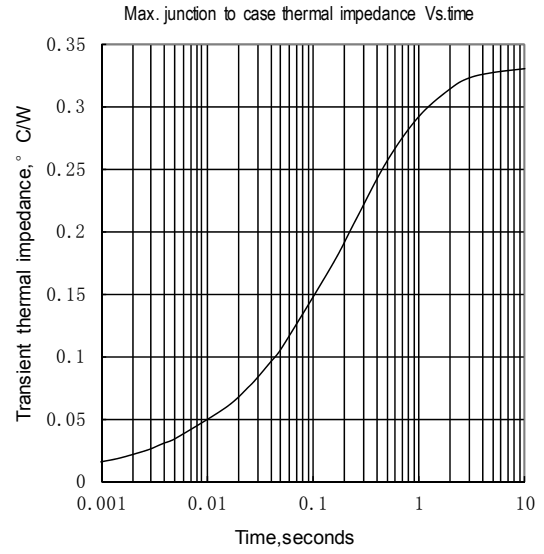


Fig.2

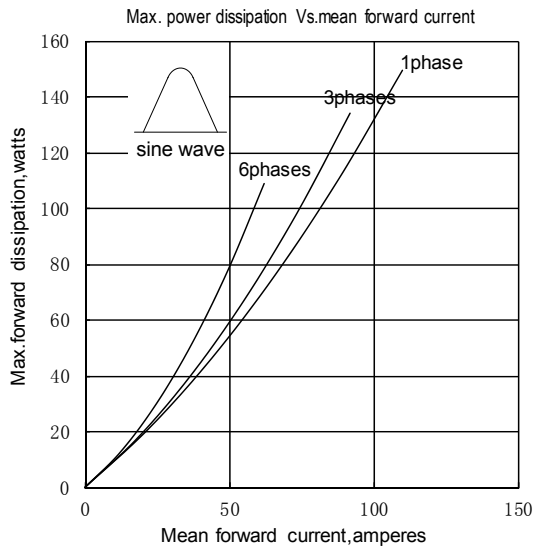


Fig.3

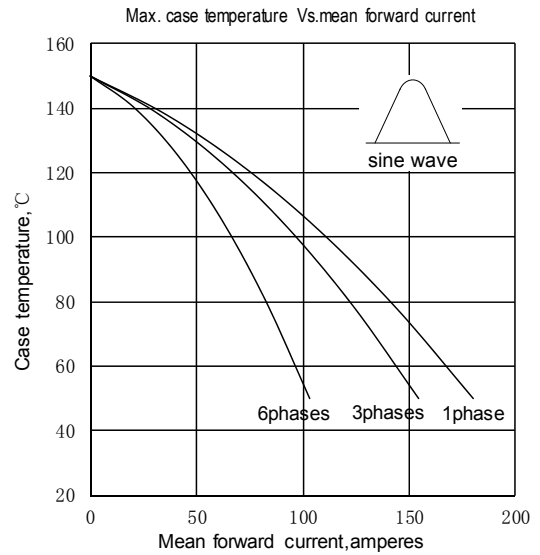


Fig.4

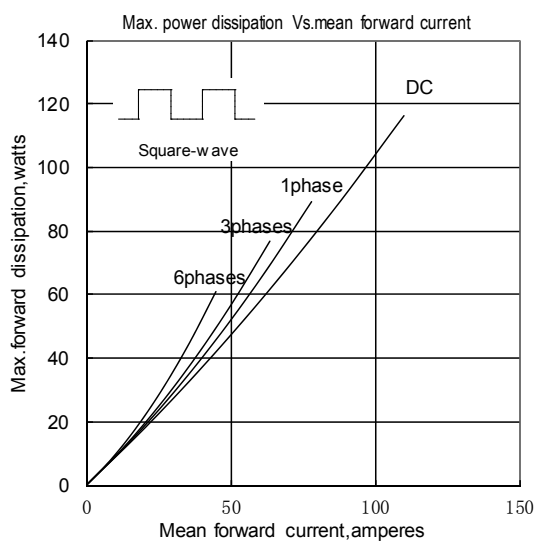


Fig.5

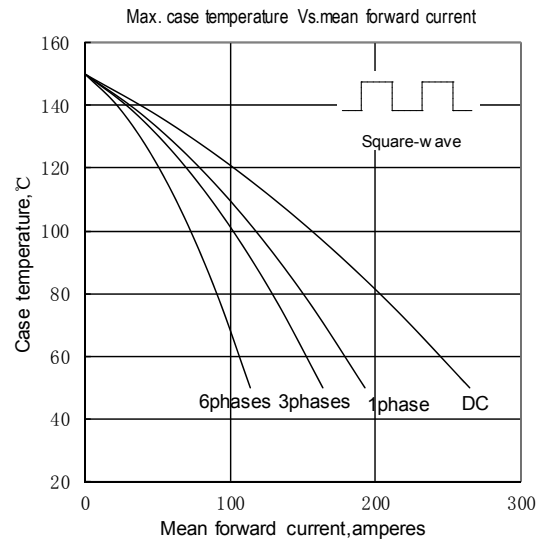


Fig.6

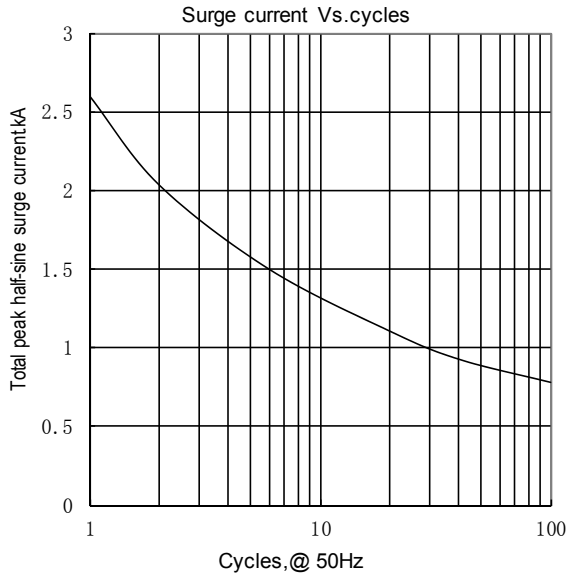


Fig.7

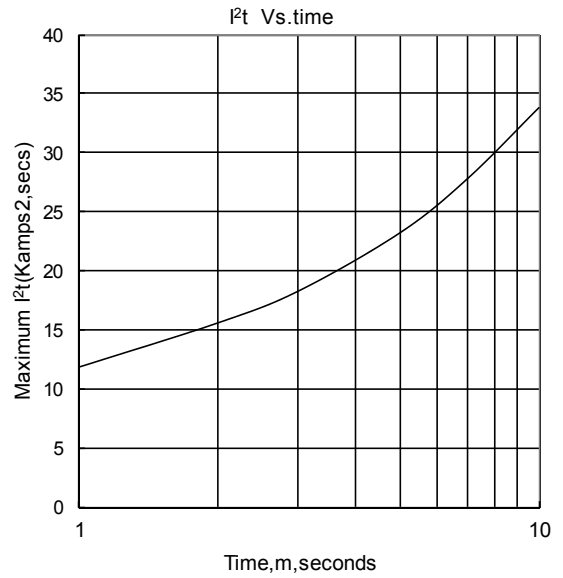


Fig.8

Outline:

